

Data Sheet

December 21, 2009

FN8179.2

Digitally Controlled Potentiometer *(XDCP*[™]*)*

intercil

The Intersil X9315 is a digitally controlled potentiometer (XDCP). The device consists of a resistor array, wiper switches, a control section, and nonvolatile memory. The wiper position is controlled by a 3-wire interface.

The potentiometer is implemented by a resistor array composed of 31 resistive elements and a wiper switching network. Between each element and at either end are tap points accessible to the wiper terminal. The position of the wiper element is controlled by the CS, U/D, and INC inputs. The position of the wiper can be stored in nonvolatile memory and then be recalled upon a subsequent power-up operation.

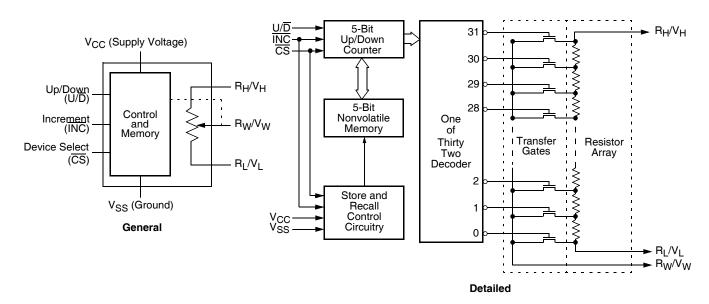
The device can be used as a three-terminal potentiometer or as a two-terminal variable resistor in a wide variety of applications including:

- Control
- Parameter Adjustments
- Signal Processing

Features

- Solid-state potentiometer
- 3-wire serial interface
- · 32 wiper tap points
 - Wiper position stored in nonvolatile memory and recalled on power-up
- 31 resistive elements
 - Temperature compensated
 - End to end resistance range ± 20%
 - Terminal voltage, 0 to V_{CC}
- Low power CMOS
 - V_{CC} = 2.7V or 5V
 - Active current, 80/400µA max.
 - Standby current, 5µA max.
- · High reliability
 - Endurance, 100,000 data changes per bit
 - Register data retention, 100 years
- R_{TOTAL} values = 10kΩ, 50kΩ, 100kΩ
- Packages
 - 8 Ld SOIC, MSOP and PDIP
- Pb-free available (RoHS compliant)

Block Diagram



Ordering Information

PART NUMBER	PART MARKING	V _{CC} LIMITS (V)	R _{TOTAL} (kΩ)	TEMP RANGE (°C)	PACKAGE	PKG. DWG. #
X9315WMZ (Note 2)	DDT	5 ±10%	10	0 to 70	8 Ld MSOP (Pb-free)	M8.118
X9315WMZT1 (Notes 1, 2)	DDT			0 to 70	8 Ld MSOP (Pb-free)	M8.118
X9315WMIT2 (Note 1)	AAX			-40 to 85	8 Ld MSOP	M8.118
X9315WMIZ (Note 2)	AKW			-40 to 85	8 Ld MSOP (Pb-free)	M8.118
X9315WMIZT1 (Notes 1, 2)	AKW			-40 to 85	8 Ld MSOP (Pb-free)	M8.118
X9315WP	X9315WP			0 to 70	8 Ld PDIP	MDP0031
X9315WST1 (Note 1)	X9315W			0 to 70	8 Ld SOIC	M8.15E
X9315WSZ (Note 2)	X9315W Z			0 to 70	8 Ld SOIC (Pb-free)	M8.15
X9315WSZT1 (Notes 1, 2)	X9315W Z			0 to 70	8 Ld SOIC (Pb-free)	M8.15
X9315WSI	X9315W I			-40 to 85	8 Ld SOIC	M8.15E
X9315WSIT1 (Note 1)	X9315W I			-40 to 85	8 Ld SOIC	M8.15E
X9315WSIZ (Note 2)	X9315W ZI			-40 to 85	8 Ld SOIC (Pb-free)	M8.15
X9315WSIZT1 (Notes 1, 2)	X9315W ZI			-40 to 85	8 Ld SOIC (Pb-free)	M8.15
X9315UMZ (Note 2)	DDS		50	0 to 70	8 Ld MSOP (Pb-free)	M8.118
X9315UMZT1 (Notes 1, 2)	DDS			0 to 70	8 Ld MSOP (Pb-free)	M8.118
X9315UMI	AEB			-40 to 85	8 Ld MSOP	M8.118
X9315UMIT1 (Notes 1, 2)	AEB			-40 to 85	8 Ld MSOP	M8.118
X9315UMIZ (Note 2)	DDR			-40 to 85	8 Ld MSOP (Pb-free)	M8.118
X9315UMIZT1 (Notes 1, 2)	DDR			-40 to 85	8 Ld MSOP (Pb-free)	M8.118
X9315UST2 (Note 1)	X9315U			0 to 70	8 Ld SOIC	M8.15E
X9315USZ (Note 2)	X9315U Z			0 to 70	8 Ld SOIC (Pb-free)	M8.15
X9315USZT1 (Notes 1, 2)	X9315U Z			0 to 70	8 Ld SOIC (Pb-free)	M8.15
X9315USIZ (Note 2)	X9315U ZI			-40 to 85	8 Ld SOIC (Pb-free)	M8.15
X9315USIZT1 (Notes 1, 2)	X9315U ZI	-		-40 to 85	8 Ld SOIC (Pb-free)	M8.15
X9315TMZ (Note 2)	DDN		100	0 to 70	8 Ld MSOP (Pb-free)	M8.118
X9315TMZT1 (Notes 1, 2)	DDN			0 to 70	8 Ld MSOP (Pb-free)	M8.118
X9315TMIZ (Note 2)	DDL			-40 to 85	8 Ld MSOP (Pb-free)	M8.118
X9315TMIZT1 (Notes 1, 2)	DDL	-		-40 to 85	8 Ld MSOP (Pb-free)	M8.118
X9315TSZ (Note 2)	X9315T Z	-		0 to 70	8 Ld SOIC (Pb-free)	M8.15
X9315TSZT1 (Notes 1, 2)	X9315T Z	-		0 to 70	8 Ld SOIC (Pb-free)	M8.15
X9315TSIZ (Note 2)	X9315T ZI	-		-40 to 85	8 Ld SOIC (Pb-free)	M8.15
X9315TSIZT1 (Notes 1, 2)	X9315T ZI	-		-40 to 85	8 Ld SOIC (Pb-free)	M8.15
X9315WMZ-2.7 (Note 2)	AOI	2.7 to 5.5	10	0 to 70	8 Ld MSOP (Pb-free)	M8.118
X9315WMZ-2.7T1 (Notes 1, 2)	AOI			0 to 70	8 Ld MSOP (Pb-free)	M8.118
X9315WMI-2.7T2 (Note 1)	AAV			-40 to 85	8 Ld MSOP	M8.118
X9315WMIZ-2.7 (Note 2)	АКХ			-40 to 85	8 Ld MSOP (Pb-free)	M8.118
X9315WMIZ-2.7T1 (Notes 1, 2)	АКХ			-40 to 85	8 Ld MSOP (Pb-free)	M8.118
X9315WS-2.7	X9315W F			0 to 70	8 Ld SOIC	M8.15E

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Ordering Information (Continued)

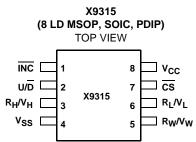
PART NUMBER	PART MARKING	V _{CC} LIMITS (V)	R _{TOTAL} (kΩ)	TEMP RANGE (°C)	PACKAGE	PKG. DWG. #
X9315WS-2.7T1 (Note 1)	X9315W F	2.7 to 5.5	10	0 to 70	8 Ld SOIC	M8.15E
X9315WSZ-2.7 (Note 2)	X9315W ZF			0 to 70	8 Ld SOIC (Pb-free)	M8.15
X9315WSZ-2.7T1 (Notes 1, 2)	X9315W ZF			0 to 70	8 Ld SOIC (Pb-free)	M8.15
X9315WSI-2.7T1 (Note 1)	X9315W G			-40 to 85	8 Ld SOIC	M8.15E
X9315WSIZ-2.7 (Note 2)	X9315W ZG			-40 to 85	8 Ld SOIC (Pb-free)	M8.15
X9315WSIZ-2.7T1 (Notes 1, 2)	X9315W ZG			-40 to 85	8 Ld SOIC (Pb-free)	M8.15
X9315UMZ-2.7 (Note 2)	AKU		50	0 to 70	8 Ld MSOP (Pb-free)	M8.118
X9315UMZ-2.7T1 (Notes 1, 2)	AKU			0 to 70	8 Ld MSOP (Pb-free)	M8.118
X9315UMIZ-2.7 (Note 2)	AJG			-40 to 85	8 Ld MSOP (Pb-free)	M8.118
X9315UMIZ-2.7T1 (Notes 1, 2)	AJG			-40 to 85	8 Ld MSOP (Pb-free)	M8.118
X9315US-2.7T2 (Note 1)	X9315U F			0 to 70	8 Ld SOIC	M8.15E
X9315USZ-2.7 (Note 2)	X9315U ZF			0 to 70	8 Ld SOIC (Pb-free)	M8.15
X9315USZ-2.7T1 (Notes 1, 2)	X9315U ZF			0 to 70	8 Ld SOIC (Pb-free)	M8.15
X9315USI-2.7	X9315U G			-40 to 85	8 Ld SOIC	M8.15E
X9315USIZ-2.7 (Note 2)	X9315U ZG			-40 to 85	8 Ld SOIC (Pb-free)	M8.15
X9315USIZ-2.7T1 (Notes 1, 2)	X9315U ZG			-40 to 85	8 Ld SOIC (Pb-free)	M8.15
X9315TMZ-2.7 (Note 2)	DDP		100	0 to 70	8 Ld MSOP (Pb-free)	M8.118
X9315TMZ-2.7T1 (Notes 1, 2)	DDP			0 to 70	8 Ld MSOP (Pb-free)	M8.118
X9315TMI-2.7T1 (Note 1)	ADY			-40 to 85	8 Ld MSOP	M8.118
X9315TMIZ-2.7 (Note 2)	DDM			-40 to 85	8 Ld MSOP (Pb-free)	M8.118
X9315TMIZ-2.7T1 (Notes 1, 2)	DDM			-40 to 85	8 Ld MSOP (Pb-free)	M8.118
X9315TSZ-2.7 (Note 2)	X9315T ZF			0 to 70	8 Ld SOIC (Pb-free)	M8.15
X9315TSZ-2.7T1 (Notes 1, 2)	X9315T ZF			0 to 70	8 Ld SOIC (Pb-free)	M8.15
X9315TSIZ-2.7 (Note 2)	X9315T ZG			-40 to 85	8 Ld SOIC (Pb-free)	M8.15
X9315TSIZ-2.7T1 (Notes 1, 2)	X9315T ZG			-40 to 85	8 Ld SOIC (Pb-free)	M8.15

NOTES:

1. Please refer to TB347 for details on reel specifications.

2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

Pin Configuration



Pin Names

SYMBOL	DESCRIPTION
R _H /V _H	High terminal
R _W /V _W	Wiper terminal
RL/VL	Low terminal
V _{SS}	Ground
V _{CC}	Supply voltage
U/D	Up/Down control input
INC	Increment control input
CS	Chip Select control input

Pin Description

R_H/V_H and R_L/V_L

The high (R_H/V_H) and low (R_L/V_L) terminals of the X9315 are equivalent to the fixed terminals of a mechanical potentiometer. The minimum voltage is V_{SS} and the maximum is V_{CC}. The terminology of R_L/V_L and R_H/V_H references the relative position of the terminal in relation to wiper movement direction selected by the U/D input, and not the voltage potential on the terminal.

R_w/V_w

 R_W/V_w is the wiper terminal and is equivalent to the movable terminal of a mechanical potentiometer. The position of the wiper within the array is determined by the control inputs. The wiper terminal series resistance is typically 200 Ω at $V_{CC} = 5V$.

Up/Down (U/D)

The U/\overline{D} input controls the direction of the wiper movement and whether the counter is incremented or decremented.

Increment (INC)

The $\overline{\text{INC}}$ input is negative-edge triggered. Toggling $\overline{\text{INC}}$ will move the wiper and either increment or decrement the counter in the direction indicated by the logic level on the U/\overline{D} input.

Chip Select (CS)

The device is selected when the \overline{CS} input is LOW. The current counter value is stored in nonvolatile memory when \overline{CS} is returned HIGH while the \overline{INC} input is also HIGH. After the store operation is complete the X9315 will be placed in the low power standby mode until the device is selected once again.

Principles of Operation

There are three sections of the X9315: the input control, counter and decode section; the nonvolatile memory; and the resistor array. The input control section operates just like an up/down counter. The output of this counter is decoded to turn on a single electronic switch connecting a point on the resistor array to the wiper output. Under the proper conditions the contents of the counter can be stored in nonvolatile memory and retained for future use. The resistor array is comprised of 31 individual resistors connected in series. At either end of the array and between each resistor is an electronic switch that transfers the connection at that point to the wiper.

The wiper, when at either fixed terminal, acts like its mechanical equivalent and does not move beyond the last position. That is, the counter does not wrap around when clocked to either extreme.

The electronic switches on the device operate in a "make before break" mode when the wiper changes tap positions. If the wiper is moved several positions, multiple taps are connected to the wiper for t_{IW} (INC to V_W change). The R_{TOTAL} value for the device can temporarily be reduced by a significant amount if the wiper is moved several positions.

When the device is powered-down, the last wiper position stored will be maintained in the nonvolatile memory. When power is restored, the contents of the memory are recalled and the wiper is set to the value last stored.

Instructions and Programming

The \overline{INC} , U/\overline{D} and \overline{CS} inputs control the movement of the wiper along the resistor array. With \overline{CS} set LOW the device is selected and enabled to respond to the U/\overline{D} and \overline{INC} inputs. HIGH to LOW transitions on \overline{INC} will increment or decrement (depending on the state of the U/\overline{D} input) a five bit counter. The output of this counter is decoded to select one of thirty two wiper positions along the resistive array.

The value of the counter is stored in nonvolatile memory whenever $\overline{\text{CS}}$ transitions HIGH while the $\overline{\text{INC}}$ input is also HIGH.

The system may select the X9315, move the wiper and deselect the device without having to store the latest wiper position in nonvolatile memory. After the wiper movement is performed as described above and once the new position is reached, the system must keep INC LOW while taking CS HIGH. The new wiper position will be maintained until

changed by the system or until a power-up/down cycle recalled the previously stored data.

This procedure allows the system to always power-up to a preset value stored in nonvolatile memory; then during system operation minor adjustments could be made. The adjustments might be based on user preference, system parameter changes due to temperature drift, etc...

The state of U/\overline{D} may be changed while \overline{CS} remains LOW. This allows the host system to enable the device and then move the wiper up and down until the proper trim is attained.

Mode Selection

CS	INC	U/D	MODE
L	~	Н	Wiper up
L	┥	L	Wiper down
_	Н	Х	Store wiper position to nonvolatile memory
Н	Х	Х	Standby
	L	Х	No store, return to standby
`	L	Н	Wiper Up (not recommended)
~	L	L	Wiper Down (not recommended)

Power-up and Down Requirements

There are no restrictions on the power-up or power-down conditions of V_{CC} and the voltages applied to the potentiometer pins provided that V_{CC} is always more positive than or equal to V_H, V_L, and V_W, i.e., V_{CC} \ge V_H, V_L, V_W. The V_{CC} ramp rate spec is always in effect.

Absolute Maximum Ratings

Temperature under bias	+135°C
Storage temperature65°C to	+150°C
Voltage on CS, INC, U/D, VH, VL and	
V _{CC} with respect to V _{SS} 1	√ to +7V
$\Delta V = V_H - V_L \dots \dots$	5V
I _W (10 seconds)	.±7.5mA

Thermal Information

Thermal Resistance (Typical, Notes 3, 4)	θ_{JA} (°C/W)	θ_{JC} (°C/W)
8 Ld SOIC	105	68
8 Ld MSOP	154	58
8 Ld PDIP	85	57
Pb-Free Reflow Profile		ee link below
http://www.intersil.com/pbfree/Pb-FreeR	leflow.asp	

Recommended Operating Conditions

Temperature (Commercial)	0°C to +70°C
Temperature (Industrial)	40°C to +85°C
Supply Voltage (V _{CC}) (Note 8) Limits	
X9315	5V ± 10%
X9315-2.7	2.7V to 5.5V
Max Wiper Current, I _W	±3.75mA
Max Power Rating	10mW

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES:

- 3. θ_{JA} is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief TB379 for details.
- 4. For $\theta_{JC},$ the "case temp" location is taken at the package top center.

			LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS/NOTES	MIN (Note 9)	TYP (Note 8)	MAX (Note 9)	UNIT
	End to end resistance tolerance		-20		+20	%
V _{VH}	V _H terminal voltage		0		V _{CC}	V
V _{VL}	V _L terminal voltage		0		V _{CC}	V
R _W	Wiper resistance	$I_W = [V(R_H) - V(R_L)]/R_{TOTAL}, V_{CC} = 5V$		200	400	Ω
R _W	Wiper resistance	$I_{W} = [V(R_{H}) - V(R_{L})]/R_{TOTAL}, V_{CC} = 2.7V$		400	1000	Ω
	Noise	Ref: 1kHz		-120		dBV
	Resolution			3		%
	Absolute linearity (Note 5)	V _{w(n)(actual)} - V _{w(n)(expected)}			±1	MI (Note 7
	Relative linearity (Note 6)	V _{w(n + 1)} - [V _{w(n) + Ml}]			±0.2	MI (Note 7
	R _{TOTAL} temperature coefficient			±300		ppm/°C
	Ratiometric temperature coefficient			±20		ppm/°C
C _H /C _L /C _W	Potentiometer capacitances	See circuit #3 on page 7		10/10/25		pF

Potentiometer Characteristics (Over recommended operating conditions unless otherwise stated.)

NOTES:

- 5. Absolute linearity is utilized to determine actual wiper voltage versus expected voltage = (V_{w(n)}(actual) V_{w(n)}(expected)) = ±1 MI Maximum.
- 6. Relative linearity is a measure of the error in step size between taps = $R_{W(n+1)} [R_{w(n)} + MI] = \pm 0.2 MI$.
- 7. 1 MI = Minimum Increment = $R_{TOT}/31$.
- 8. Typical values are for $T_A = +25^{\circ}C$ and nominal supply voltage.

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9. Parameters with MIN and/or MAX limits are 100% tested at +25°C, unless otherwise specified. Temperature limits established by characterization and are not production tested.

SYMBOL	PARAMETER	TEST CONDITIONS	MIN (Note 9)	TYP (Note 8)	MAX (Note 9)	UNIT	
V _{CC}	Supply Voltage	X9315	4.5		5.5	V	
		X9315-2.7	2.7		5.5	V	
I _{CC1}	V _{CC} active current (Increment)	$\overline{CS} = V_{IL}, U/\overline{D} = V_{IL} \text{ or } V_{IH} \text{ and } \overline{INC} = 0.4V$ @ max. t _{CYC}			80	μA	
I _{CC2}	V _{CC} active current (Store) (EEPROM Store)	$\overline{CS} = V_{IH}, U/\overline{D} = V_{IL} \text{ or } V_{IH} \text{ and } \overline{INC} = V_{IH} @$ max. t _{WR}			400	μA	
I _{SB}	Standby supply current	$\overline{\text{CS}}$ = V_{CC} - 0.3V, U/\overline{\text{D}} and $\overline{\text{INC}}$ = V_{SS} or V_{CC} - 0.3V			5	μA	
ILI	CS, INC, U/D input leakage current	$V_{IN} = V_{SS}$ to V_{CC}	-10		+10	μA	
VIH	CS, INC, U/D input HIGH voltage		V _{CC} x 0.7		V _{CC} + 0.5	V	
V_{IL}	CS, INC, U/D input LOW voltage		-0.5		V _{CC} x 0.1	V	
C _{IN}	CS, INC, U/D input capacitance	$V_{CC} = 5V$, $V_{IN} = V_{SS}$, $T_A = +25^{\circ}C$, $f = 1MHz$		10		pF	

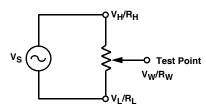
DC Electrical Specifications (Over recommended operating conditions unless otherwise specified.

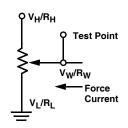
Endurance and Data Retention

PARAMETER	MIN	UNIT
Minimum endurance	100,000	Data changes per bit
Data retention	100	Years

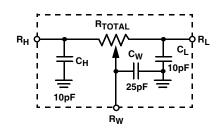
Test Circuit #1

Test Circuit #2





Circuit #3 SPICE Macro Model



AC Conditions of Test

Input pulse levels	0V to 3V
Input rise and fall times	10ns
Input reference levels	1.5V

AC Electrical Specifications (Over recommended operating conditions unless otherwise specified)

		LIMITS				
SYMBOL	PARAMETER	MIN (Note 9)	TYP (Note 8)	MAX (Note 9)	UNIT	
t _{CI}	CS to INC setup	100			ns	
t _{ID}	INC HIGH to U/D change	100			ns	
t _{DI}	U/D to INC setup	2.9			μs	
t _{IL}	INC LOW period	1			μs	
tн	INC HIGH period	1			μs	

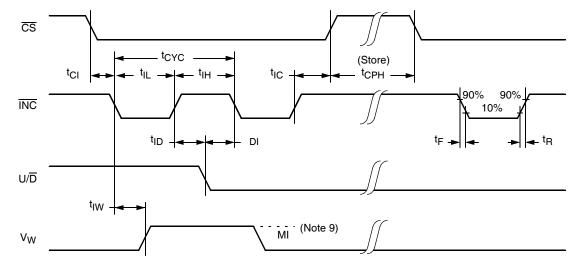
SYMBOL		LIMITS				
	PARAMETER	MIN (Note 9)	TYP (Note 8)	MAX (Note 9)	UNIT	
^t IC	INC Inactive to CS inactive	1			μs	
t _{CPH}	CS Deselect time (NO STORE)	100			ns	
t _{CPH}	CS Deselect time (STORE)	10			ms	
t _{IW}	INC to Vw change		1	5	μs	
^t CYC	INC cycle time	4			μs	
t _{R,} t _F (Note 10)	INC input rise and fall time			500	μs	
t _{PU} (Note 10)	Power-up to wiper stable			5	μs	
t _R V _{CC} (Note 10)	V _{CC} power-up rate	0.2		50	V/ms	
twR	Store cycle		5	10	ms	

AC Electrical Specifications (Over recommended operating conditions unless otherwise specified) (Continued)

NOTE:

10. This parameter is not 100% tested.

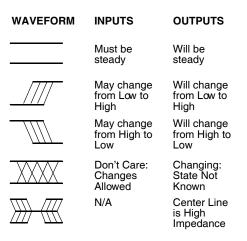
AC Timing



NOTE:

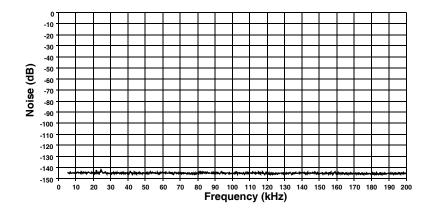
11. MI in the A.C. timing diagram refers to the minimum incremental change in the V_W output due to a change in the wiper position.

Symbol Table

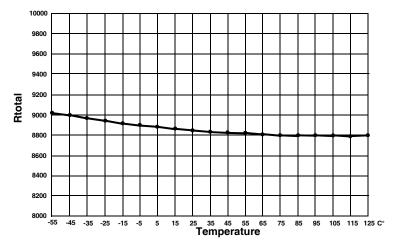


Performance Characteristics (Typical)

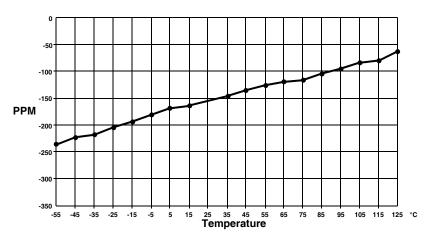
Typical Noise

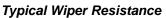


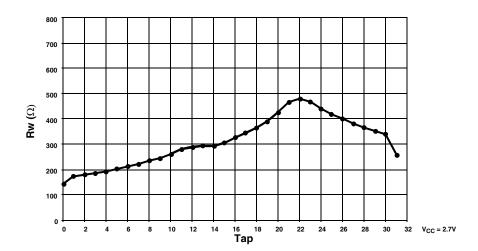
Typical Rtotal vs. Temperature



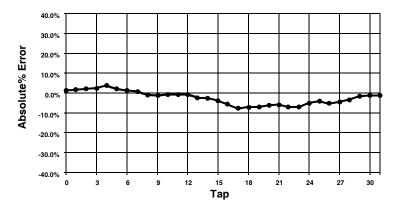
Typical Total Resistance Temperature Coefficient



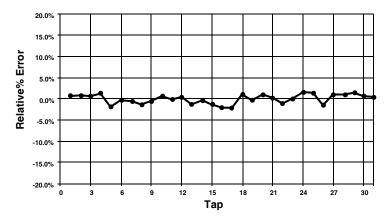




Typical Absolute% Error per Tap Position



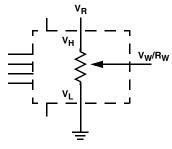
Typical Relative% Error per Tap Position



Applications Information

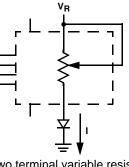
Electronic digitally controlled (XDCP) potentiometers provide three powerful application advantages; (1) the variability and reliability of a solid-state potentiometer, (2) the flexibility of computer-based digital controls, and (3) the retentivity of nonvolatile memory used for the storage of multiple potentiometer settings or data.

Basic Configurations of Electronic Potentiometers

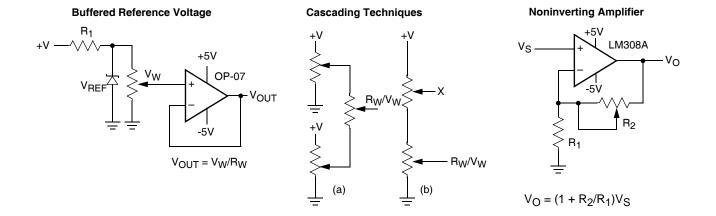


Three terminal potentiometer; variable voltage divider

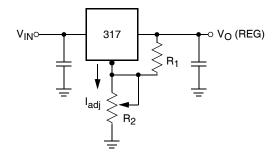
Basic Circuits



Two terminal variable resistor; variable current

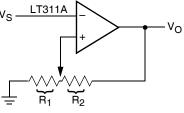


Voltage Regulator



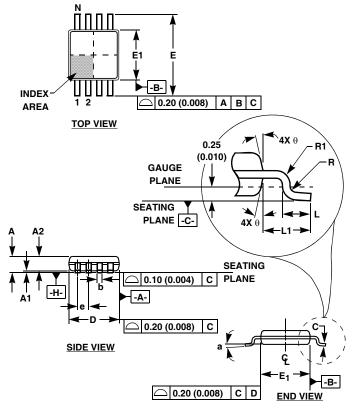
 $V_O (REG) = 1.25V (1 + R_2/R_1) + I_{adj} R_2$

Comparator with Hysteresis



$$\begin{split} V_{UL} &= \{R_1/(R_1 + R_2)\} \; V_O(max) \\ V_{LL} &= \{R_1/(R_1 + R_2)\} \; V_O(min) \end{split}$$

(for additional circuits see AN115)



Mini Small Outline Plastic Packages (MSOP)

NOTES:

- 1. These package dimensions are within allowable dimensions of JEDEC MO-187BA.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1994.
- 3. Dimension "D" does not include mold flash, protrusions or gate burrs and are measured at Datum Plane. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- 4. Dimension "E1" does not include interlead flash or protrusions and are measured at Datum Plane. -H- Interlead flash and protrusions shall not exceed 0.15mm (0.006 inch) per side.
- 5. Formed leads shall be planar with respect to one another within 0.10mm (0.004) at seating Plane.
- 6. "L" is the length of terminal for soldering to a substrate.
- 7. "N" is the number of terminal positions.
- 8. Terminal numbers are shown for reference only.
- 9. Dimension "b" does not include dambar protrusion. Allowable dambar protrusion shall be 0.08mm (0.003 inch) total in excess of "b" dimension at maximum material condition. Minimum space between protrusion and adjacent lead is 0.07mm (0.0027 inch).
- 10. Datums -A and -B to be determined at Datum plane - H -
- 11. Controlling dimension: MILLIMETER. Converted inch dimensions are for reference only.

M8.118 (JEDEC MO-187AA)

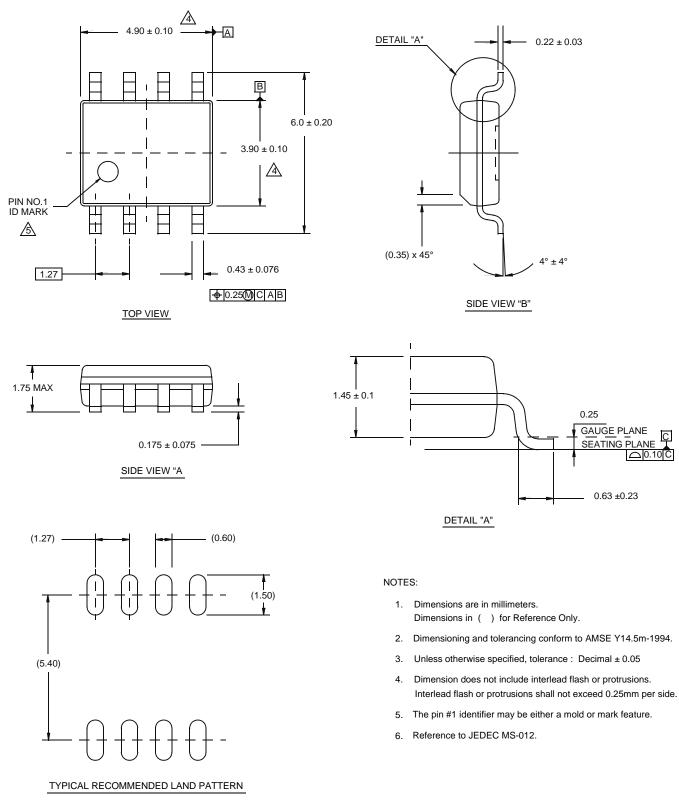
8 LEAD MINI SMALL OUTLINE PLASTIC PACKAGE

,	MAX	MIN		
		IVIIIN	MAX	NOTES
	0.043	0.94	1.10	-
2	0.006	0.05	0.15	-
)	0.037	0.75	0.95	-
)	0.014	0.25	0.36	9
	0.008	0.09	0.20	-
;	0.120	2.95	3.05	3
j	0.120	2.95	3.05	4
0.026 BSC		0.65 BSC		-
'	0.199	4.75	5.05	-
j	0.028	0.40	0.70	6
0.037 REF		0.95 REF		-
8		8		7
;	-	0.07	-	-
1	-	0.07	-	-
	15 ⁰	5 ⁰	15 ⁰	-
	6 ⁰	0 ⁰	6 ⁰	-
3	3	15 ⁰	15 [°] 5 [°]	15 ⁰ 5 ⁰ 15 ⁰

Package Outline Drawing

M8.15E

8 LEAD NARROW BODY SMALL OUTLINE PLASTIC PACKAGE Rev 0, 08/09





 0.22 ± 0.03

 $4^{\circ} \pm 4^{\circ}$

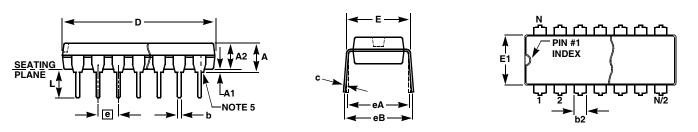
0.25

GAUGE PLANE

0.63 ±0.23

0.10 C

Plastic Dual-In-Line Packages (PDIP)



MDP0031 PLASTIC DUAL-IN-LINE PACKAGE

SYMBOL	PDIP8	PDIP14	PDIP16	PDIP18	PDIP20	TOLERANCE	NOTES
А	0.210	0.210	0.210	0.210	0.210	MAX	
A1	0.015	0.015	0.015	0.015	0.015	MIN	
A2	0.130	0.130	0.130	0.130	0.130	±0.005	
b	0.018	0.018	0.018	0.018	0.018	±0.002	
b2	0.060	0.060	0.060	0.060	0.060	+0.010/-0.015	
С	0.010	0.010	0.010	0.010	0.010	+0.004/-0.002	
D	0.375	0.750	0.750	0.890	1.020	±0.010	1
E	0.310	0.310	0.310	0.310	0.310	+0.015/-0.010	
E1	0.250	0.250	0.250	0.250	0.250	±0.005	2
е	0.100	0.100	0.100	0.100	0.100	Basic	
eA	0.300	0.300	0.300	0.300	0.300	Basic	
eB	0.345	0.345	0.345	0.345	0.345	±0.025	
L	0.125	0.125	0.125	0.125	0.125	±0.010	
Ν	8	14	16	18	20	Reference	

NOTES:

Rev. B 2/99

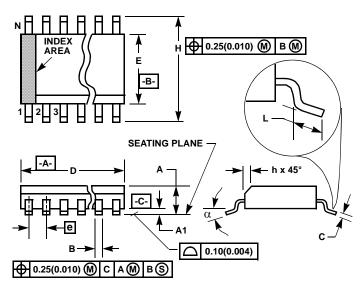
1. Plastic or metal protrusions of 0.010" maximum per side are not included.

2. Plastic interlead protrusions of 0.010" maximum per side are not included.

3. Dimensions E and eA are measured with the leads constrained perpendicular to the seating plane.

- 4. Dimension eB is measured with the lead tips unconstrained.
- 5. 8 and 16 lead packages have half end-leads as shown.

Small Outline Plastic Packages (SOIC)



NOTES:

- 1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
- 5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
- 6. "L" is the length of terminal for soldering to a substrate.
- 7. "N" is the number of terminal positions.
- 8. Terminal numbers are shown for reference only.
- 9. The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
- 10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

M8.15 (JEDEC MS-012-AA ISSUE C) 8 LEAD NARROW BODY SMALL OUTLINE PLASTIC PACKAGE

	INC	HES	MILLIN		
SYMBOL	MIN	MAX	MIN	MAX	NOTES
А	0.0532	0.0688	1.35	1.75	-
A1	0.0040	0.0098	0.10	0.25	-
В	0.013	0.020	0.33	0.51	9
С	0.0075	0.0098	0.19	0.25	-
D	0.1890	0.1968	4.80	5.00	3
E	0.1497	0.1574	3.80	4.00	4
е	0.050 BSC		1.27 BSC		-
Н	0.2284	0.2440	5.80	6.20	-
h	0.0099	0.0196	0.25	0.50	5
L	0.016	0.050	0.40	1.27	6
Ν	8		8		7
α	0°	8°	0°	8°	-

Rev. 1 6/05

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